# imall

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# HMC482ST89 / 482ST89E

RoHS Designer's Kit Designer's Kit Available

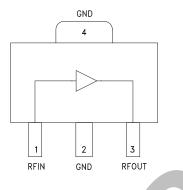
#### **Typical Applications**

The HMC482ST89 / HMC482ST89E is an ideal RF/IF gain block & LO or PA driver for:

v04.0710

- Cellular / PCS / 3G
- Fixed Wireless, WLAN & WiMAX
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

#### **Functional Diagram**



### SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz

#### Features

P1dB Output Power: +22 dBm Gain: 20 dB Output IP3: +36 dBm Cascadable 50 Ohm I/Os Single Supply: +6V to +12V Industry Standard SOT89 Package Included in the HMC-DK001 Designer's Kit

#### **General Description**

The HMC482ST89 & HMC482ST89E are SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 5 GHz. Packaged in an industry standard SOT89, the amplifier can be used as a cascadable 50 Ohm RF/IF gain stage as well as a LO or PA driver with up to +24 dBm output power. The Darlington feedback pair results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

#### Electrical Specifications, Vs= 8.0 V, Rbias= 27 Ohm, $T_{A} = +25^{\circ}$ C

Parameter		Min.	Тур.	Max.	Units
Gain	DC - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz 3.0 - 4.0 GHz 4.0 - 5.0 GHz	17 15 12.5 10 8	19 17 14.5 12 10		dB dB dB dB dB
Gain Variation Over Temperature	DC - 5 GHz		0.008	0.016	dB/ °C
Input Return Loss	DC - 1.0 GHz 1.0 - 5.0 GHz		15 18		dB dB
Output Return Loss	DC - 1.0 GHz 1.0 - 3.0 GHz 3.0 - 4.0 GHz 4.0 - 5.0 GHz		20 14 12 8		dB dB dB dB
Reverse Isolation	DC - 5 GHz		16		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz 3.0 - 4.0 GHz 4.0 - 5.0 GHz	19.5 17 14.5 12.5 10.5	22.5 20 17.5 15.5 13.5		dBm dBm dBm dBm dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	0.5 - 1.0 GHz 1.0 - 2.0 GHz 2.0 - 3.0 GHz 3.0 - 4.0 GHz 4.0 - 5.0 GHz		36 35 32 30 28		dBm dBm dBm dBm dBm
Noise Figure	DC - 2.0 GHz 2.0 - 4.0 GHz 4.0 - 5.0 GHz		4 5 5.5		dB dB dB
Supply Current (Icq)			110		mA

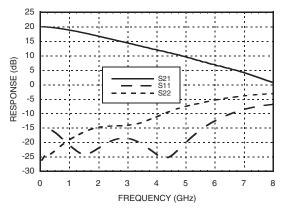
Note: Data taken with broadband bias tee on device output.

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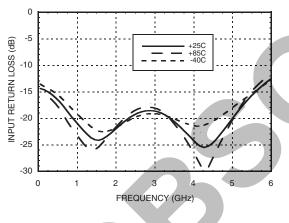




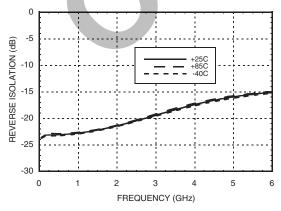
#### **Broadband Gain & Return Loss**



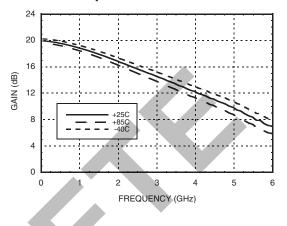
Input Return Loss vs. Temperature



**Reverse Isolation vs. Temperature** 



Gain vs. Temperature

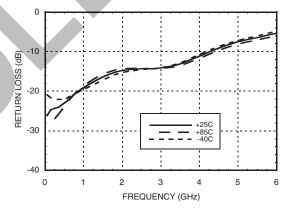


HMC482ST89 / 482ST89E

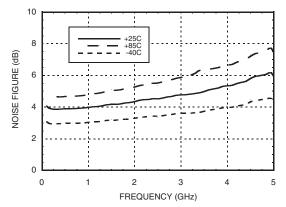
MMIC AMPLIFIER, DC - 5 GHz

SiGe HBT GAIN BLOCK

**Output Return Loss vs. Temperature** 



#### Noise Figure vs. Temperature

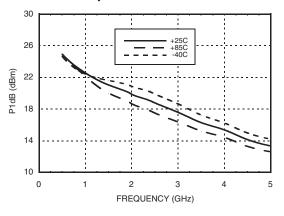


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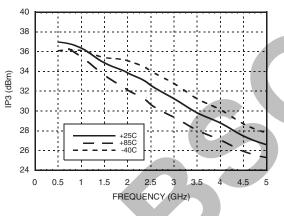




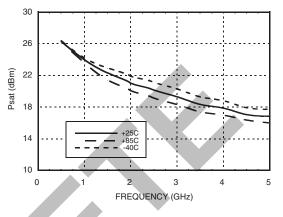
#### P1dB vs. Temperature



**Output IP3 vs. Temperature** 



#### Psat vs. Temperature

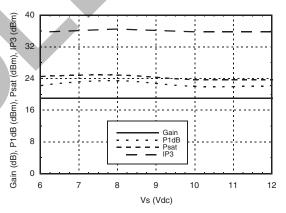


HMC482ST89 / 482ST89E

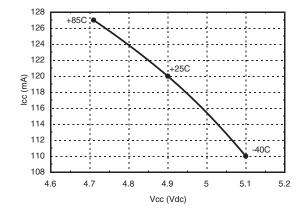
MMIC AMPLIFIER, DC - 5 GHz

SiGe HBT GAIN BLOCK

Gain, Power & OIP3 vs. Supply Voltage for Constant Icc= 110 mA @ 850 MHz







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#### Absolute Maximum Ratings

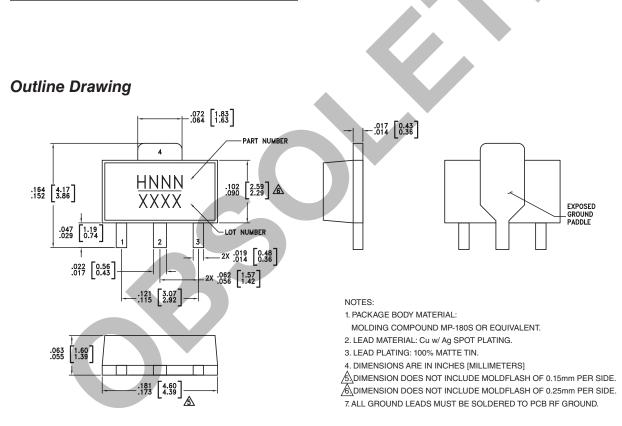
	-
Collector Bias Voltage (Vcc)	+6.0 Vdc
RF Input Power (RFIN)(Vcc = +5 Vdc)	+14 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 14.5 mW/°C above 85 °C)	0.94 W
Thermal Resistance (junction to lead)	69 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



HMC482ST89 / 482ST89E

MMIC AMPLIFIER, DC - 5 GHz

SiGe HBT GAIN BLOCK



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]	
HMC482ST89	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H482 XXXX	
HMC482ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>H482</u> XXXX	

[1] Max peak reflow temperature of 235  $^\circ\text{C}$ 

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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## HMC482ST89 / 482ST89E

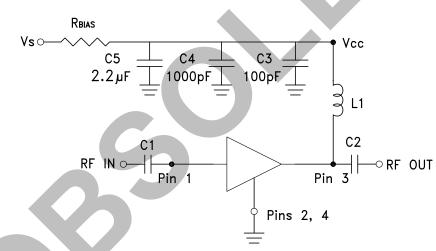
### SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz



#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	RFOUT
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins and package bottom must be connected to RF/ DC ground.	

#### Application Circuit



# Recommended Bias Resistor Values for Icc= 110 mA, Rbias= (Vs - Vcc) / Icc

Supply Voltage (Vs)	6V	8V	10V	12V
RBIAS VALUE	9.1 Ω	27 Ω	47 Ω	62 Ω
RBIAS POWER RATING	1/4 W	1/2 W	1 W	1.5 W

Note:

- 1. External blocking capacitors are required on RFIN and RFOUT.
- 2. RBIAS provides DC bias stability over temperature.

#### **Recommended Component Values for Key Application Frequencies**

Component	Frequency (MHz)						
Component	50	900	1900	2200	2400	3500	5000
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH	6.8 nH
C1, C2	0.01 µF	100 pF					

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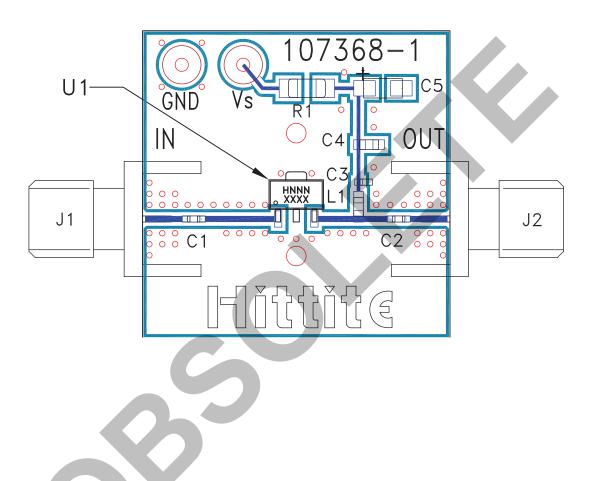


### HMC482ST89 / 482ST89E

### SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 109026 [1]

Item	Description		
J1 - J2	PCB Mount SMA Connector		
J3 - J4	DC Pin		
C1, C2	Capacitor, 0402 Pkg.		
C3	100 pF Capacitor, 0402 Pkg.		
C4	1000 pF Capacitor, 0603 Pkg.		
C5	2.2 µF Capacitor, Tantalum		
R1	Resistor, 1210 Pkg.		
L1	Inductor, 0603 Pkg.		
U1	HMC482ST89 / HMC482ST89E		
PCB [2]	107368 Evaluation PCB		

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

8 AMPLIFIERS - DRIVER & GAIN BLOCK - SMT

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